NSN 5961-00-594-1854

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View Online at https://aerobasegroup.com/nsn/5961-00-594-1854 **Inclosure Material:** Metal **Overall Length:** 2.500 inches **End Application:** Missile, air launch cruise (alcm) agm-86b; radar set It air traffic control (17m jul 83) (an/tps-63); 485 tacs **Mounting Facility Quantity:** 1 **Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.031 inches **Thread Size:** 0.500 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 nonrepetitive peak reverse voltage, peak total value and 1000.0 repetitive peak reverse voltage and 5.0 peak negative gate voltage **Current Rating Per Characteristic:** 70.00 amperes forward current, average and 1200.00 amperes forward current, average preset and 4.00 amperes forward current, total rms of standard range **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn; weapon system essential **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 3 tab, solder lug Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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